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DS3008-2.0

## ZN429E8/ZN429D LOW COST 8-BIT D-A CONVERTER

The ZN429 is a monolithic 8-bit D-A converter containing an R-2R ladder network of diffused resistors with precision bipolar switches.

#### **FEATURES**

- Linearity Error  $\pm^{1}/_{2}$  LSB
- Single +5V Supply
- Low Power Consumption 25mW Typical
- Settling Time 1 Microsecond Typical
- TTL and 5V CMOS Compatible
- Designed for Low Cost Applications

#### **ABSOLUTE MAXIMUM RATINGS**

Supply voltage,  $V_{CC}$  +7.0V Max. voltage, logic and  $V_{REF}$  inputs +5.5V Storage temperature range -55°C to +125°C

#### **ORDERING INFORMATION**

Ambient operating temperature -40°C to +85°C Package, ZN429D MP14 Package, ZN429E8 DP14

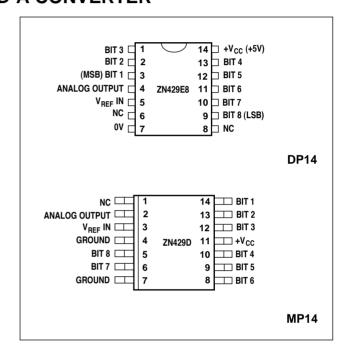
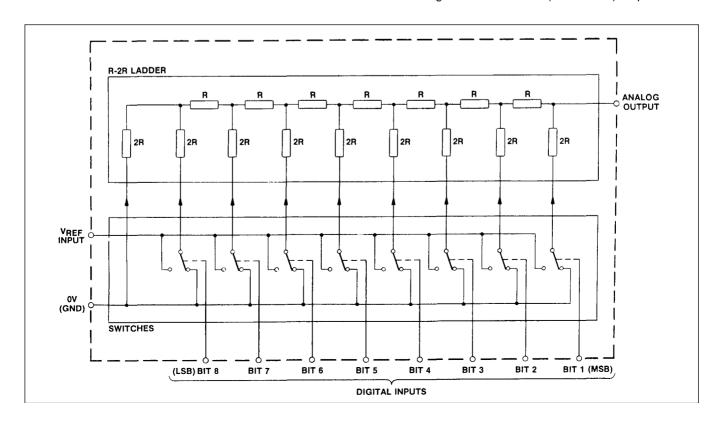


Fig.1 Pin connections (not to scale) - top view



#### **ZN429**

#### **ELECTRICAL CHARACTERISTICS**

(at  $T_{amb} = 25$ °C and  $V_{CC} = +5V$  unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Converter Resolution		8	-	-	bits	
Accuracy		8	-	-	bits	
Non-linearity		-	-	±0.5	LSB	
Differential non-linearity		-	±0.5	-	LSB	Note 1
Settling time to 0.5LSB		-	1.0	-	μs	1 LSB step
Settling time to 0.5LSB		-	2.0	-	μs	All bits ON to OFF or OFF to ON
Offset voltage ZN429E8, ZN429D	Vos	-	3.0	5.0	mV	All bits OFF
V <sub>OS</sub> temperature coefficient		-	5	-	μV/°C	
Full-scale output		2.545	2.550	2.555	V	All bits ON Ext. V <sub>REF</sub> = 2.56V
Full-scale temp. coefficient		-	3	-	ppm/°C	Ext. V <sub>REF</sub> = 2.560V
Non-linearity temp. coefficient		-	7.5	-	ppm/°C	Relative to F.S.R.
Analog output resistance	R <sub>O</sub>	-	10	-	kΩ	
External reference voltage		0	-	3.0	V	
Supply voltage	V <sub>CC</sub>	4.5	-	5.5	V	
Supply current	I <sub>S</sub>	-	5	9	mA	
High level input voltage	V <sub>IH</sub>	2.0	-	-	V	
Low level input voltage	V <sub>IL</sub>	-	-	0.7	V	
High level input current	I <sub>IH</sub>	-	-	10	μΑ	V <sub>CC</sub> = max. V <sub>I</sub> = 2.4V
		-	-	100	μΑ	$V_{CC} = max.$ $V_{I} = 5.5V$
Low level input current	I <sub>IL</sub>	-	-	-0.18	mA	$V_{CC} = max.$ $V_{I} = 0.3V$

NOTE 1: Monotonic over full temperature range.

#### INTRODUCTION

The ZN429 is an 8-bit D-A converter. It contains an advanced design of R-2R ladder network and an array of precision bipolar switches on a single monolithic chip.

The special design of the ladder network results in full 8-bit accuracy using normal diffused resistors.

The converter is of the voltage switching type and uses an R-2R resistor ladder network as shown in Fig.3.

Each 2R element is connected either to 0V or  $V_{REF}$  by transistor switches specially designed for low offset voltage (typically 1mV).

Binary weighted voltages are produced at the output of the R-2R ladder, the value depending on the digital number applied to the bit inputs.

An external fixed or varying reference is required which should have a slope resistance less than  $2\Omega.$ 

Suggested external reference sources are the ZN404 or one of the ZN458 range. Each ZN404 is capable of supplying up to five ZN429 circuits and this is increased to ten for the ZN458 range.

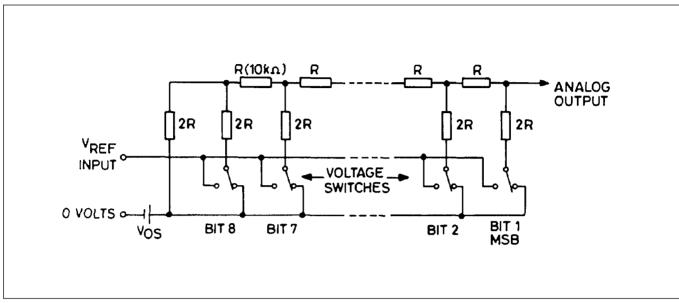


Fig.3 The R-2R ladder network

#### **APPLICATIONS**

#### (1) Unipolar D-A Converter

The nominal output range of the ZN429 is 0 to  $V_{\mbox{\scriptsize REF IN}}$ through a  $10\Omega$  resistance. Other output ranges can readily be obtained by using an external amplifier.

The resulting full-scale range is given by

$$V_{OUT FS} = (1 + \frac{R1}{R2}) V_{REF IN} = G.V_{REF IN}$$

The impedance at the inverting input is R1//R2 and for low drift with temperature this parallel combination should be equal to the ladder resistance (10k $\Omega$ ). The required nominal values of R1 and R2 are given by R1 =  $10\text{Gk}\Omega$  and R<sub>2</sub> =  $10\text{G}/(\text{G-1})\text{k}\Omega$ .

$$R1 = 10Gk\Omega$$
 and  $R_2 = 10G/(G-1)k\Omega$ 

Using these relationships a table of nominal resistance values for  $R_1$  and  $R_2$  can be constructed for  $V_{REF\ IN} = 2.5V$ .

Output Range	G	R <sub>1</sub>	R <sub>2</sub>
+5V	2	20kΩ	20kΩ
+10V	4	40kΩ	13.33kΩ

For gain setting R<sub>1</sub> is adjusted about its nominal value. Practical circuit realisations (including amplifier stabilising components) for +5 and +10V output ranges are given in Fig.5. Settling time for a major transition is 2.5µs typical.

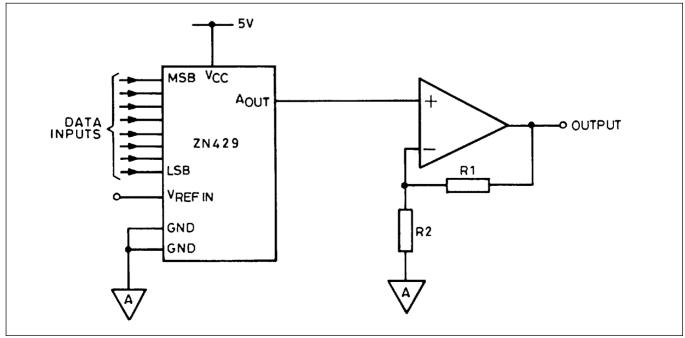


Fig.4 Unipolar operation - basic circuit

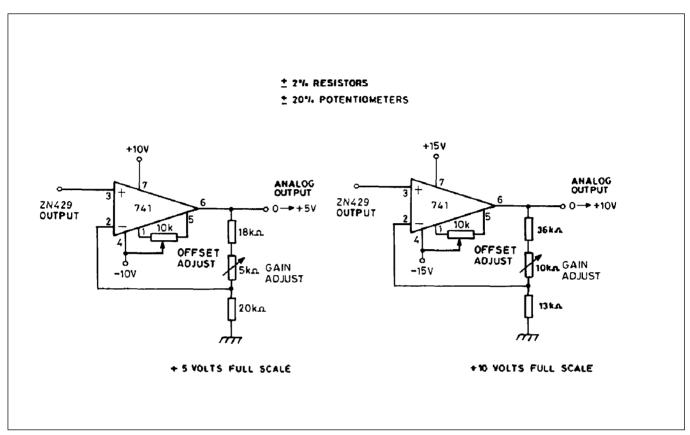


Fig.5 Unipolar operation - component values

#### UNIPOLAR ADJUSTMENT PROCEDURE

(i) Set all bits to OFF (LOW) and adjust zero until  $\ensuremath{\text{V}_{\text{OUT}}} = 0.0000\ensuremath{\text{V}}.$ 

(ii) Set all bits ON (HIGH) and adjust gain until  $V_{OUT} = FS - 1LSB$ .

#### **UNIPOLAR SETTING UP POINTS**

Output Range, +FS	LSB	FS - 1LSB
+5V	19.5 mV	4.9805V
+10V	39.1mV	9.9609V

1LSB = <u>FS</u>

#### **UNIPOLAR LOGIC CODING**

Input Code	Analog Output
(Binary)	(Nominal Value)
1111111 11111110 11000000 10000001 1000000	FS - 1LSB FS - 2 LSB <sup>3</sup> / <sub>4</sub> FS <sup>1</sup> / <sub>2</sub> FS + 1LSB <sup>1</sup> / <sub>2</sub> FS <sup>1</sup> / <sub>2</sub> FS - 1LSB <sup>1</sup> / <sub>4</sub> FS 1LSB

#### (2) Bipolar D-A Converter

For bipolar operation the output from the ZN429 is offset by half full-scale by connecting a resistor R3 between  $V_{REF}$  and the inverting input of the buffer amplifier (Fig.6).

When the digital input of the ZN429 is zero the analog output is zero and the amplifier output should be -full-scale. An input of all ones to the D-A will give a ZN429 output of  ${\stackrel{\Omega}{-}}$   $V_{REF\ IN}$  and the amplifier output required is +full-scale. Also, to match the ladder resistance the parallel combination of  $R_1,\ R_2$  and  $R_3$  should be  $10k\Omega.$ 

The nominal values of  $\ensuremath{R_1},\,\ensuremath{R_2}$  and  $\ensuremath{R_3}$  which meet these conditions are given by

R1 =  $20Gk\Omega$ , R2 =  $20G/(G-1)k\Omega$  and R3 =  $20k\Omega$ .

where the resultant output range is  $\pm G.V_{REF\ IN}.$ 

Assuming that  $V_{REF\ IN}=2.5V$  the nominal values of resistors for  $\pm 5$  and  $\pm 10V$  output ranges are given in the following table:

Output Range	G	R <sub>1</sub>	R <sub>2</sub>	R <sub>3</sub>
±5V	2	40kΩ	40kΩ	20kΩ
±10V	4	80kΩ	26.67kΩ	20kΩ

Minus full scale (0FFSET) is set by adjusting R1 about its nominal value relative to R3. Plus full-scale (GAIN) is set by adjusting R2 relative to R1.

Settling time for a major transistion is 2.5µs typical.

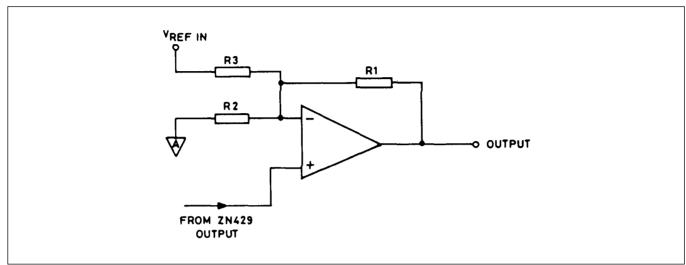


Fig.6 Bipolar operation - basic circuit

#### **BIPOLAR ADJUSTMENT PROCEDURE**

# (i) Set all bits to OFF (LOW) and adjust OFFSETuntil the amplifier output reads -FULL-SCALE.

(ii) Set all bits ON (HIGH) and adjust gain until the amplifier reads +(FULL-SCALE - 1LSB).

#### **BIPOLAR SETTING UP POINTS**

Input Range, ± FS	LSB	-FS	+(FS - 1LSB)
±5V	39.1 mV	-5.0000V	+4.9609V
±10V	78.1mV	-10.0000V	9.9219V

1LSB = <u>2FS</u> 256

#### **BIPOLAR LOGIC CODING**

Input Code	Analog Output
(Offset Binary)	(Nominal Value)
1111111 11111110 11000000 10000001 1000000	+(FS - 1LSB) +(FS - 2 LSB) + <sup>1</sup> / <sub>2</sub> FS + 1LSB 0 -1 LSB - <sup>1</sup> / <sub>2</sub> FS -(FS - 1LSB)

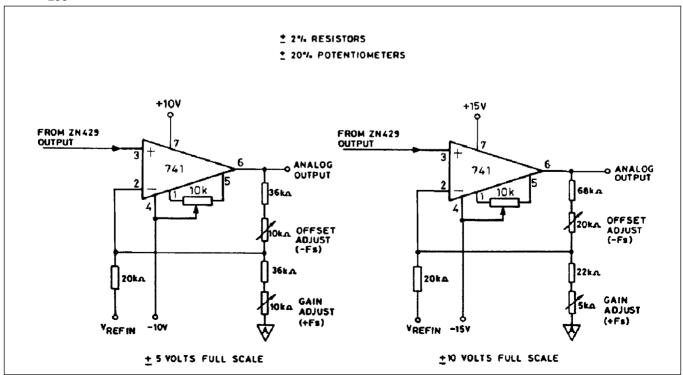


Fig.7 Bipolar operation - component values

#### **ZN429**



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